Special Issue

Challenges and Applications of Non-volatile Memory

Message from the Guest Editor

The miniaturization of modern, cheaper electronics with a reduced power consumption is channelizing classical physics into the quantum domain. Among several others, non-volatile memories are one of the driving forces of this enormous development over the past few decades. This opens up new opportunities and applications of non-volatile memories to serve the future with a realistic view. In this Special Issue, we are particularly interested in high-quality submissions that highlight the current and future trends of flash memory; advances in emerging memory technologies, such as phase change memory, resistive random-access memory, ferroelectric memory, and so on; and emerging applications of non-volatile memories, addressing the recent breakthroughs in two-dimensional (2D) material systems for memory applications. The topics of interest include, but are not limited to, the following:

- Flash present and future
- Emerging nonvolatile memories
- Emerging devices and computing technology
- Emerging devices and security
- Non-volatile memories for biotechnology
- 2D materials and memory devices
- Failure analysis of non-volatile memories

Welcome to contribute.

Guest Editor

Dr. Writam Banerjee

Semiconductor Integrated Device and Process Lab, Pohang University of Science and Technology, Pohang, Republic of Korea

Deadline for manuscript submissions

closed (31 October 2020)

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Electronics
Editorial Office
MDPI, Grosspeteranlage 5
4052 Basel, Switzerland
Tel: +41 61 683 77 34
electronics@mdpi.com

mdpi.com/journal/electronics

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About the Journal

Message from the Editor-in-Chief

Electronics is a multidisciplinary journal designed to appeal to a diverse audience of research scientists, practitioners, and developers in academia and industry. The journal is devoted to fast publication of latest technological breakthroughs, cutting-edge developments, and timely reviews of current and emerging technologies related to the broad field of electronics. Experimental and theoretical results are published as regular peer-reviewed articles or as articles within Special Issues guest-edited by leading experts in selected topics of interest.

Editor-in-Chief

Prof. Dr. Flavio Canavero
Department of Electronics and Telecommunications, Politecnico di Torino, 10129 Torino, Italy

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